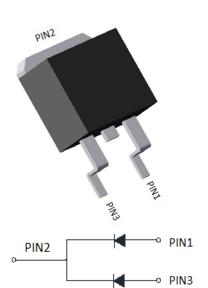




# **Schottky Diodes**



#### **Features**

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- •Meets MSL level 1, per J-STD-020, LF maximum peak of 260 ℃

#### **Typical Applications**

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

#### **Mechanical Data**

• Package: TO-263

Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant

Tauring, Rons-compilant

 Terminals: Tin plated leads, solderable per J-STD-002 and JESD22-B102

• Polarity: As marked

#### ■Maximum Ratings (Ta=25°C Unless otherwise specified)

-maximum ratings (ru = = = = = = = = = = = = = = = = = = =							
PARAMETER	SYMBOL	UNIT	MBRB3020CT	MBRB3035CT	MBRB3045CT	MBRB3050CT	MBRB3060CT
Device marking code			MBRB3020CT	MBRB3035CT	MBRB3045CT	MBRB3050CT	MBRB3060CT
Repetitive Peak Reverse Voltage	VRRM	V	20	35	45	50	60
Average Rectified Output Current @60Hz sine wave, R-load, TC (FIG.1)	IO	Α	30				
Surge(Non-repetitive)Forward Current @60H <sub>Z</sub> half sine-wave, 1 cycle, T <sub>a</sub> =25°C	IFSM	Α	200				
Current Squared Time @1ms≤t<8.3ms Tj=25 °C	l <sup>2</sup> t	A <sup>2</sup> s	167				
Storage Temperature	T <sub>stg</sub>	$^{\circ}$	-55 ~ +175				
Junction Temperature	Tj	$^{\circ}$	-55 ~ +150		+175		

#### **■Electrical Characteristics** (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBRB3020CT	MBRB3035CT	MBRB3045CT	MBRB3050CT	MBRB3060CT
Maximum instantaneous forward voltage drop per diode	VFM	V	IFM=15.0A	0.65		0.75		
Maximum DC reverse current at rated DC blocking voltage per	IRRM1	A	VRM=VRRM T <sub>a</sub> =25℃			0.1		
diode IRRM2		mA	VRM=VRRM T <sub>a</sub> =100°C	20				

Note1:Pulse test:300uS pulse widh,1% duty cycle

Note2:Pulse test:pulse widh 40mS

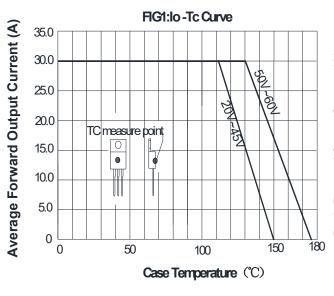
#### **■Thermal Characteristics** (T<sub>a</sub>=25°C Unless otherwise specified)

PA	RAMETER	SYMBOL	UNIT	MBRB3020CT	MBRB3035CT	MBRB3045CT	MBRB3050CT	MBRB3060CT
Thermal Resistance	Between junction and case	R <sub>θJ-C</sub>	°CMV			2.0		

## **■Ordering Information** (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBRB3020CT THRU MBRB3060CT	Approximate 1.43	50	2000	8000	Tube

### **■Characteristics** (Typical)



**FIG2:Surge Forward Current Capability** 

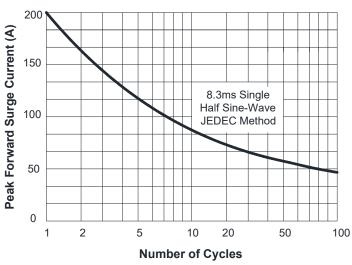


FIG3: Forward Voltage

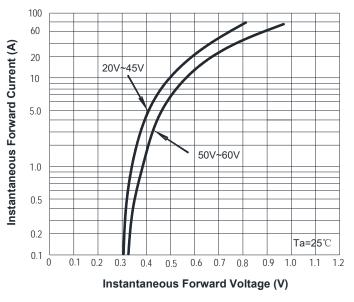
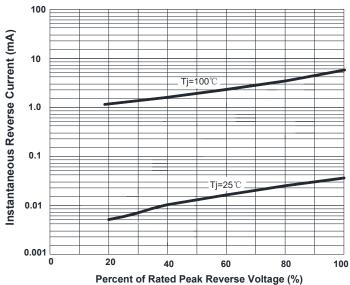
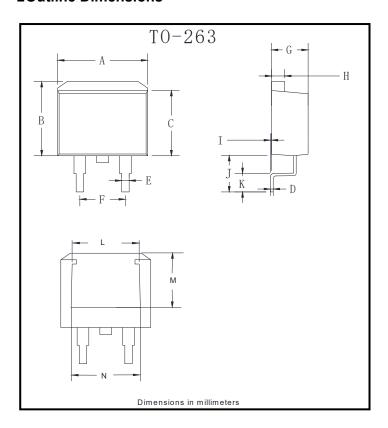


FIG.4: Typical Reverse Characteristics



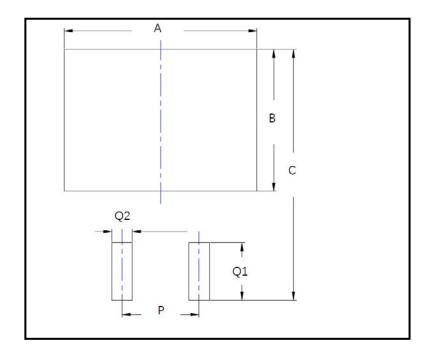


#### **■**Outline Dimensions



TO-263					
Dim	Min	Max			
Α	9.5	11.5			
В	9.7	10.5			
С	8.4	9.0			
D	0.28	0.64			
Е	0.68	0.94			
F	4.55	5.6			
G	4.04	5.10			
Н	1.14	1.4			
I	0	0.2			
J	4.9	6.05			
K	1.79	2.79			
L	7.3	7.9			
М	6.2	6.8			
N	7.6	8.2			

## **■**Suggested Pad Layout



Dim	Millimeters
Α	12.7
В	9.4
С	16.6
Р	5.08
Q1	3.8
Q2	1.35



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